

# **isc Silicon NPN Darlington Power Transistor**

**BU921P** 

### **DESCRIPTION**

- High Voltage
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **APPLICATIONS**

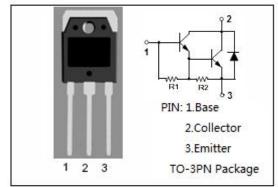
• Designed for automotive ignition applications and inverter circuits for motor control.

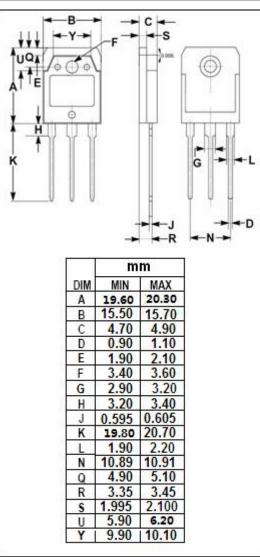
## ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

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SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CES</sub>	Collector-Emitter Voltage V <sub>BE</sub> = 0	450	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	400	V	
V <sub>EBO</sub>	Emitter-Base Voltage	5	V	
Ic	Collector Current	10	Α	
Ісм	Collector Current-peak	15	Α	
I <sub>B</sub>	Base Current	5	Α	
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C	105	W	
T <sub>j</sub>	Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature Range	-65~150	$^{\circ}$ C	

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case		°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	400			V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 50mA			1.8	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	Ic= 7A; I <sub>B</sub> = 140mA			1.8	V
V <sub>BE</sub> (sat)-1	Base-Emitter Saturation Voltage	I <sub>C</sub> = 5A; I <sub>B</sub> = 50mA			2.2	V
V BE(sat)-2	Base-Emitter Saturation Voltage	I <sub>C</sub> = 7A; I <sub>B</sub> = 140mA			2.5	V
Ices	Collector Cutoff Current	V <sub>CE</sub> = 450V;V <sub>BE</sub> = 0 V <sub>CE</sub> = 450V;V <sub>BE</sub> = 0;T <sub>j</sub> = 125℃			0.25 0.5	mA
I <sub>CEO</sub>	Collector Cutoff Current	V <sub>CE</sub> = 400V; I <sub>B</sub> = 0			0.25	mA
І <sub>ЕВО</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			50	mA
V <sub>ECF</sub>	C-E Diode Forward Voltage	I <sub>F</sub> = 7A			2.5	V

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